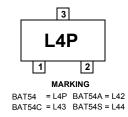
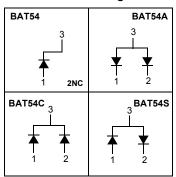


# BAT54/A/C/S Schottky Diodes





### **Connection Diagram**



# Absolute Maximum Ratings \* Ta = 25°C unless otherwise noted

Symbol	Parameter	Value	Unit
V <sub>RRM</sub>	Maximum Repetitive Reverse Voltage	30	V
I <sub>F(AV)</sub>	Average Rectified Forward Current	200	mA
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second	600	mA
T <sub>STG</sub>	Storage Temperature Range	-55 to +150	°C
$T_J$	Operating Junction Temperature	-55 to +150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### **Thermal Characteristics**

Symbol	Parameter	Value	Unit
$P_{D}$	Power Dissipation	290	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	430	°C/W

## **Electrical Characteristics** $T_C = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max.	Units
$V_R$	Breakdown Voltage	I <sub>R</sub> = 10μA	30		V
V <sub>F</sub>	Forward Voltage	$I_F = 0.1\text{mA}$ $I_F = 1\text{mA}$ $I_F = 10\text{mA}$ $I_F = 30\text{mA}$ $I_F = 100\text{mA}$		240 320 400 500 0.8	mV mV mV V
I <sub>R</sub>	Reverse Leakage	V <sub>R</sub> = 25V		2	μΑ
C <sub>T</sub>	Total Capacitance	$V_R = 1V$ , $f = 1.0MHz$		10	pF
t <sub>rr</sub>	Reverse Recovery Time	$I_F = I_R = 10 \text{mA}, I_{RR} = 1.0 \text{mA},$ $R_L = 100 \Omega$		5.0	ns

## **Typical Performance Characteristics**

Figure 1. Forward Voltage vs Temperature

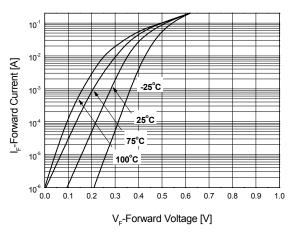


Figure 2. Reverse Leakage Current vs Temperature

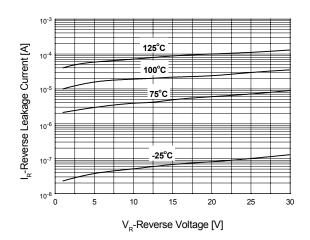
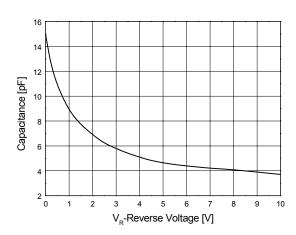


Figure 3. Capacitance vs Reverse Bias Voltage



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FACT™	ImpliedDisconnect™	OCX™	RapidConfigure <sup>™</sup>	TruTranslation™
FACT Quiet Series™		OCXPro™	RapidConnect™	UHC™
Across the board. Around the world.™ The Power Franchise® Programmable Active Droop™		OPTOLOGIC <sup>®</sup> OPTOPLANAR™ PACMAN™	μSerDes™ SILENT SWITCHER <sup>®</sup> SMART START™	UltraFET <sup>®</sup> UniFET™ VCX™

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